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Frm 1449 (Modified)	Atty Docket No.	Application No.:
` · · · · ·	UNTYP017	10/612,263
Information Disclosure	Applicant:	
Statement By Applicant	Rinerson et al.	
,	Filing Date	Group
(Use Several Sheets if Necessary)	July 1, 2003	2818

## **U.S. Patent Documents**

Examiner						Sub-	Filing
Initial	No.	Patent No.	Date	Patentee	Class	class	Date
The	A	6,204,139	2001-03-20	Liu et al.			
70	В	5,920,500	1999-07-06	Tehrani et al.			
	C	6,545,891	2003-04-08	Tringali et al.			
	D	6,504,753	2003-01-07	Scheuerlein et al.			
	E	6,483,736	2002-11-19	Johnson et al.			
	F	6,385,074	2002-05-07	Johnson et al.			
	G	6,351,406	2002-02-26	Johnson et al.			
	H	6,185,122	2001-02-06	Johnson et al.			
	I	6,034,882	2000-03-07	Johnson et al.			
<u> </u>	J	5,835,396	1998-11-10	Zhang			
100	K	4,442,507	1994-04-10	Roesner			

U.S. Published Patent Applications

Examiner		Document	Publication	Inventor
Initial	No.	No.	Date	
Tow	J	2002/0000597 A·1	01/03/02	Okazawa
/A./	K	2001/0023992 A1	09/27/01	Doll

## Other Documents

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication		
M	L	Beck, A. et al., "Reproducible switching effect in thin oxide films for memory applications", Applied Physics Letters, Vol. 77, No. 1, 3 July 2000,139-141.		
	М	Rossel, C. et al., "Electrical current distribution across a metal-insulator-metal structure during bistable switching", Journal of Applied Physics, Vol. 90, No. 6, 15 September 2001, 2892-2898.		
Bu	N	Watanabe, Y. et al., "Current-driven insulator-conductor transition and nonvolatile memory in chromium-doped SrTiO <sub>3</sub> single crystals", Applied Physics Letters, Vol. 78, No. 23, 4 June 2001, 3738-3740.		
Examiner 7	VA	JT. NGUYEN Date Considered 2/7/05		

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



## Form 1449 (Modified)

Information Disclosure Statement By Applicant

(Use Several Sheets if Necessary)

Atty Docket No.

UNTYP017

Applicant: Rinerson et al.

Filing Date

July 1, 2003

Application No.:

10/612,263

Group

Group 2824

## **Other Documents**

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication		
Du	Α.	Liu, S.Q., et al., "Electric-pulse-induced reversible resistance change effect in magnetoresistive films", Applied Physics Letters, Vol. 76, No. 19, 8 May 2000, 2749-2651.		
Bu	В	Liu, S.Q., et al., "A New Concept For Non-Volatile Memory: Electric-Pulse Induced Reversible Resistance Change Effect In Magnetoresistive Films", Space Vacuum Epitaxy Center, University of Huston, Huston TX, 7 Pages.		
Examiner 7	UA.	N 7. NGUYEN Date Considered 2/7/05		

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.